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FAIRCHILD

SEMICONDUCTOR

April 2007

FDS6298

30V N-Channel Fast Switching PowerTrench[®] MOSFET

General Description

This N-Channel MOSFET has been designed specifically to improve the overall efficiency of DC/DC converters using either synchronous or conventional switching PWM controllers. It has been optimized for low gate charge, low $R_{DS(ON)}$ and fast switching speed.

Applications

- Control Switch for DC-DC Buck converters
- Notebook Vcore



Features

■ 13 A, 30 V.

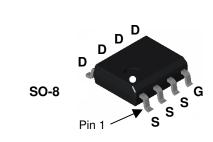
Low Rg (1 Ohm)

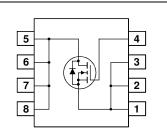
ROHS Compliant

■ Low gate charge (10nC @ V_{GS}=5V)

■ Very low Miller Charge (3nC)

Telecom / Networking Point of Load





 $R_{DS(ON)} = 9 \text{ m}\Omega @ V_{GS} = 10 \text{ V}$

 $R_{\text{DS(ON)}} = 12 \ m\Omega \ @ \ V_{\text{GS}} = 4.5 \ V$

Absolute Maximum Ratings Ta=25°C unless otherwise noted

Symbol	Parameter			Ratings	Units	
V _{DSS}	Drain-Source Voltage			30	V	
V _{GSS}	Gate-Source Voltage			±20	V	
ID	Drain Currei	nt – Continuous	(Note 1a)	13	Α	
		– Pulsed		50	A	
P _D	Power Dissi	pation for Single Operation	(Note 1a)	3.0	14/	
	Power Dissi	pation for Single Operation	(Note 1b)	1.2	W	
E _{AS}	Single Pulse Avalanche Energy		(Note 3)	181	mJ	
T _J , T _{STG}	Operating and Storage Junction Temperature Range			-55 to +150	°C	
Therma	I Charact	eristics				
R _{eJA}	Thermal Resistance, Junction-to-Ambient (Note 1a)			50	°C/W	
R _{eJA}	Thermal Resistance, Junction-to-Ambient		ent (Note 1b)	125	°C/W	
R _{eJC}	Thermal Resistance, Junction-to-Case (Note 1)		(Note 1)	25	°C/W	
Packag	e Marking	g and Ordering In	formation		· · · · ·	
Device Marking		Device	Reel Size	Tape width	Quantity	
FDS6298				12mm	2500 units	

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Symbol	Parameter	Test Conditions	Min	Тур	Max	Units
Off Char	acteristics		l			1
BV _{DSS}	Drain–Source Breakdown Voltage	$V_{GS} = 0 V, I_D = 250 \mu A$	30	-	-	V
$\frac{\Delta BV_{DSS}}{\Delta T_J}$	Breakdown Voltage Temperature Coefficient	$I_D = 250 \ \mu\text{A}$, Referenced to 25°C	-	30	-	mV/°C
I _{DSS}	Zero Gate Voltage Drain Current	$V_{DS} = 24 V, V_{GS} = 0 V$	-	-	1	μA
I _{GSS}	Gate-Body Leakage	$V_{GS} = \pm 20 \text{ V}, V_{DS} = 0 \text{ V}$	-	-	±100	nA
On Chara	acteristics (Note 2)					
$V_{\text{GS(th)}}$	Gate Threshold Voltage	$V_{DS} = V_{GS}, I_D = 250 \ \mu A$	1	1.7	3	V
$\frac{\Delta V_{GS(th)}}{\Delta T_J}$	Gate Threshold Voltage Temperature Coefficient	$I_D = 250 \ \mu\text{A}$, Referenced to 25°C	-	-5	-	mV/°C
R _{DS(ON)}	$ \begin{array}{l} \mbox{Static Drain-Source} \\ \mbox{On-Resistance} \end{array} & \begin{array}{l} \mbox{V}_{\rm GS} = 10 \mbox{ V}, \mbox{ I}_{\rm D} = 13 \mbox{ A} \\ \mbox{V}_{\rm GS} = 4.5 \mbox{ V}, \mbox{ I}_{\rm D} = 12 \mbox{ A} \\ \mbox{V}_{\rm GS} = 10 \mbox{ V}, \mbox{ I}_{\rm D} = 13 \mbox{ A}, \mbox{ T}_{\rm J} = 125^{\circ} \mbox{C} \end{array} $		-	7.4 9.4 11	9 12 15	mΩ
g _{FS}	Forward Transconductance	$V_{DS} = 10 \text{ V}, \text{ I}_{D} = 13 \text{ A}$	-	58	-	S
Dynamic	Characteristics	•				
Ciss	Input Capacitance			1108	-	pF
Coss	Output Capacitance	$V_{DS} = 15 V, V_{GS} = 0 V,$	-	310	-	pF
Crss	Reverse Transfer Capacitance	f = 1.0 MHz	-	109	-	pF
R _G	Gate Resistance	$V_{GS} = 15 \text{ mV}, \text{ f} = 1.0 \text{ MHz}$	0.3	1	1.7	Ω
Switchin	g Characteristics (Note 2)					
t _{d(on)}	Turn-On Delay Time		-	11	20	ns
tr	Turn–On Rise Time	$V_{DD} = 15 V, I_D = 1 A,$	-	5	10	ns
t _{d(off)}	Turn-Off Delay Time	$V_{GS} = 10 \text{ V}, \text{ R}_{GEN} = 6 \Omega$	-	27	43	ns
t _f	Turn-Off Fall Time		-	7	14	ns
Qg	Total Gate Charge		-	10	14	nC
Q _{gs}	Gate-Source Charge	$V_{DS} = 15 \text{ V}, \text{ I}_{D} = 13 \text{ A},$ - $V_{GS} = 5 \text{ V}$	-	3	-	nC
Q _{gd}	Gate-Drain Charge	$\nabla GS = 5 V$	-	3	-	nC
Drain-So	ource Diode Characteristics	•				•
V _{SD}	Drain–Source Diode Forward Voltage	$V_{GS} = 0 \ V, \ I_S = 2.1 \ A$ (Note 2)	-	0.74	1.2	V
t _{rr}	Diode Reverse Recovery Time	$I_F = 13 \text{ A}, dI_F/dt = 100 \text{ A}/\mu\text{s}$	-	27	-	ns
Q _{rr}	Diode Reverse Recovery Charge		_	13	-	nC

Notes:

1. R_{BJA} is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins. R_{BJC} is guaranteed by design while R_{BCA} is determined by the user's board design.



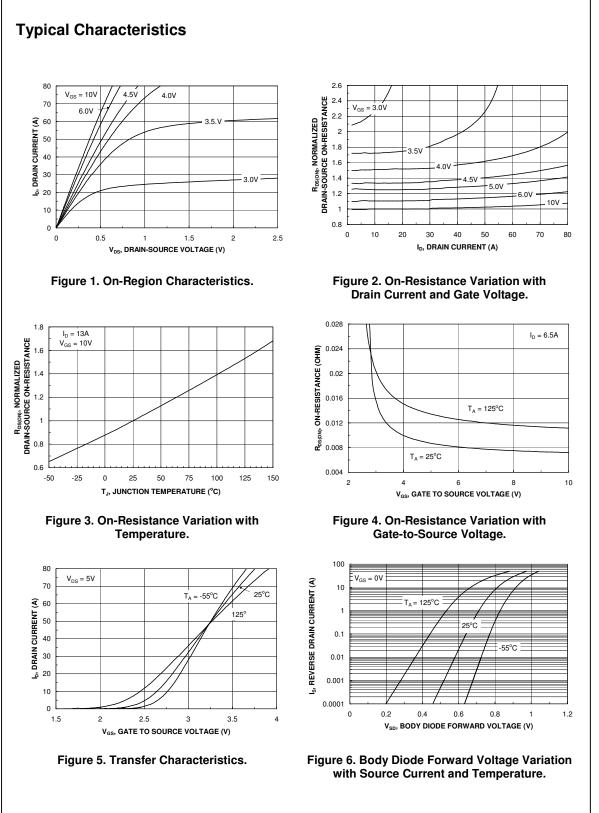
 a) 50 °C/W when mounted on a 1in² pad of 2 oz copper



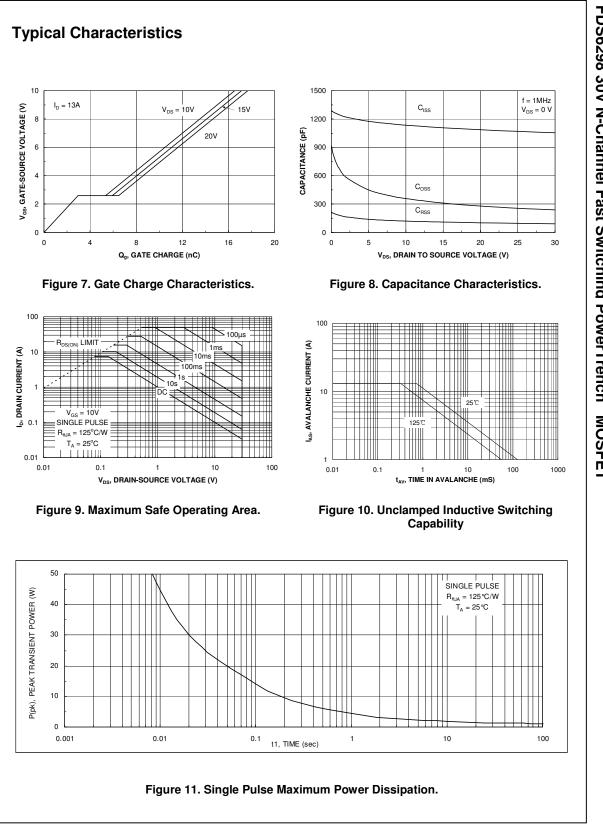
b) 125℃/W when mounted on a minimum pad.

Scale 1 : 1 on letter size paper

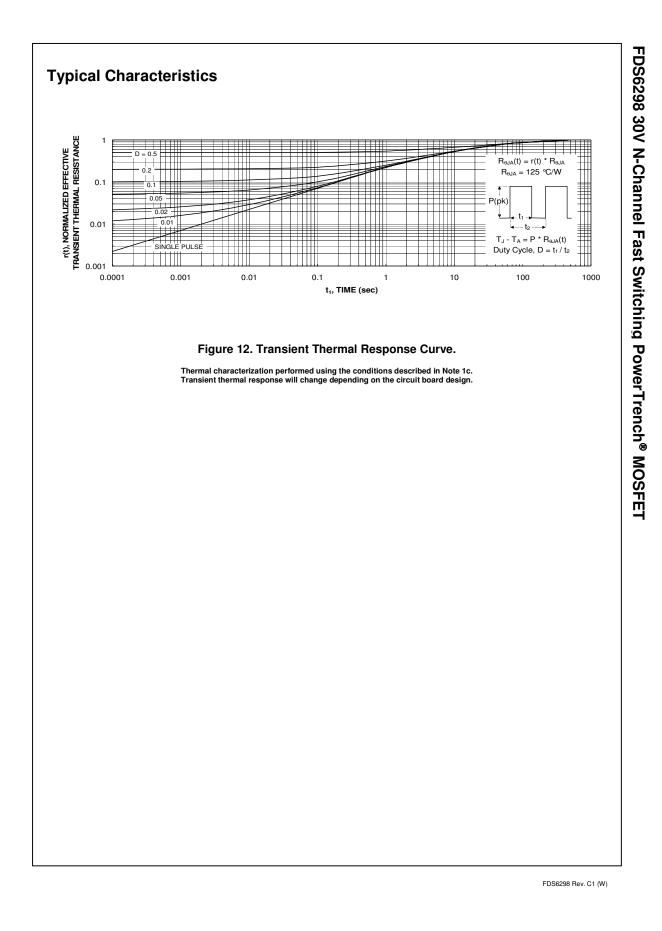
2. Test: Pulse Width < 300μs, Duty Cycle < 2.0% 3. Starting TJ = 25°C, L = 3mH, I_{AS} = 11A, V_{DD} = 30V, V_{GS} = 10V



FDS6298 30V N-Channel Fast Switching PowerTrench[®] MOSFET



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